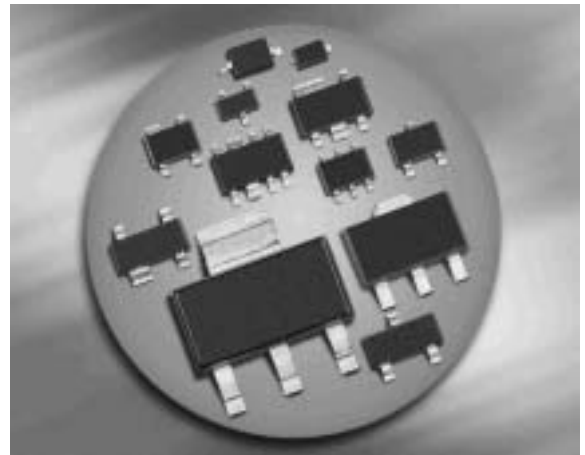
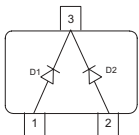


## Silicon Switching Diode

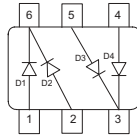
- For high-speed switching applications
- Common cathode configuration
- BAV70S / U: For orientation in reel see package information below
- Pb-free (RoHS compliant) package<sup>1)</sup>
- Qualified according AEC Q101



### BAV70 BAV70W



### BAV70S BAV70U



| Type   | Package | Configuration         | Marking |
|--------|---------|-----------------------|---------|
| BAV70  | SOT23   | common cathode        | A4s     |
| BAV70S | SOT363  | double common cathode | A4s     |
| BAV70U | SC74    | double common cathode | A4s     |
| BAV70W | SOT323  | common cathode        | A4s     |

<sup>1</sup>Pb-containing package may be available upon special request

**Maximum Ratings** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                 | Symbol    | Value       | Unit             |
|-------------------------------------------|-----------|-------------|------------------|
| Diode reverse voltage                     | $V_R$     | 80          | V                |
| Peak reverse voltage                      | $V_{RM}$  | 85          |                  |
| Forward current                           | $I_F$     | 200         | mA               |
| Non-repetitive peak surge forward current | $I_{FSM}$ |             | A                |
| $t = 1 \mu\text{s}$                       |           | 4.5         |                  |
| $t = 1 \text{ ms}$                        |           | 1           |                  |
| $t = 1 \text{ s single}$                  |           | 0.5         |                  |
| $t = 1 \text{ s double}$                  |           | 0.75        |                  |
| Total power dissipation                   | $P_{tot}$ |             | mW               |
| BAV70, $T_S \leq 33^\circ\text{C}$        |           | 250         |                  |
| BAV70S, $T_S \leq 85^\circ\text{C}$       |           | 250         |                  |
| BAV70U, $T_S \leq 90^\circ\text{C}$       |           | 250         |                  |
| BAV70W, $T_S \leq 103^\circ\text{C}$      |           | 250         |                  |
| Junction temperature                      | $T_j$     | 150         | $^\circ\text{C}$ |
| Storage temperature                       | $T_{stg}$ | -65 ... 150 |                  |

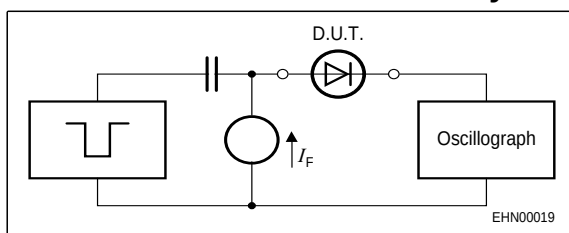
#### Thermal Resistance

| Parameter                                | Symbol     | Value      | Unit |
|------------------------------------------|------------|------------|------|
| Junction - soldering point <sup>1)</sup> | $R_{thJS}$ |            | K/W  |
| BAV70                                    |            | $\leq 460$ |      |
| BAV70S                                   |            | $\leq 260$ |      |
| BAV70U                                   |            | $\leq 240$ |      |
| BAV70W                                   |            | $\leq 190$ |      |

<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

| Parameter                                                                                               | Symbol     | Values                |                       |                                    | Unit    |
|---------------------------------------------------------------------------------------------------------|------------|-----------------------|-----------------------|------------------------------------|---------|
|                                                                                                         |            | min.                  | typ.                  | max.                               |         |
| DC Characteristics                                                                                      |            |                       |                       |                                    |         |
| Breakdown voltage<br>$I_{(BR)} = 100 \mu A$                                                             | $V_{(BR)}$ | 85                    | -                     | -                                  | V       |
| Reverse current<br>$V_R = 70 V$<br>$V_R = 25 V, T_A = 150 ^\circ C$<br>$V_R = 70 V, T_A = 150 ^\circ C$ | $I_R$      | -<br>-<br>-           | -<br>-<br>-           | 0.15<br>30<br>50                   | $\mu A$ |
| Forward voltage<br>$I_F = 1 mA$<br>$I_F = 10 mA$<br>$I_F = 50 mA$<br>$I_F = 100 mA$<br>$I_F = 150 mA$   | $V_F$      | -<br>-<br>-<br>-<br>- | -<br>-<br>-<br>-<br>- | 715<br>855<br>1000<br>1200<br>1250 | mV      |
| AC Characteristics                                                                                      |            |                       |                       |                                    |         |
| Diode capacitance<br>$V_R = 0 V, f = 1 MHz$                                                             | $C_T$      | -                     | -                     | 1.5                                | pF      |
| Reverse recovery time<br>$I_F = 10 mA, I_R = 10 mA$ , measured at $I_R = 1mA$ ,<br>$R_L = 100 \Omega$   | $t_{rr}$   | -                     | -                     | 4                                  | ns      |

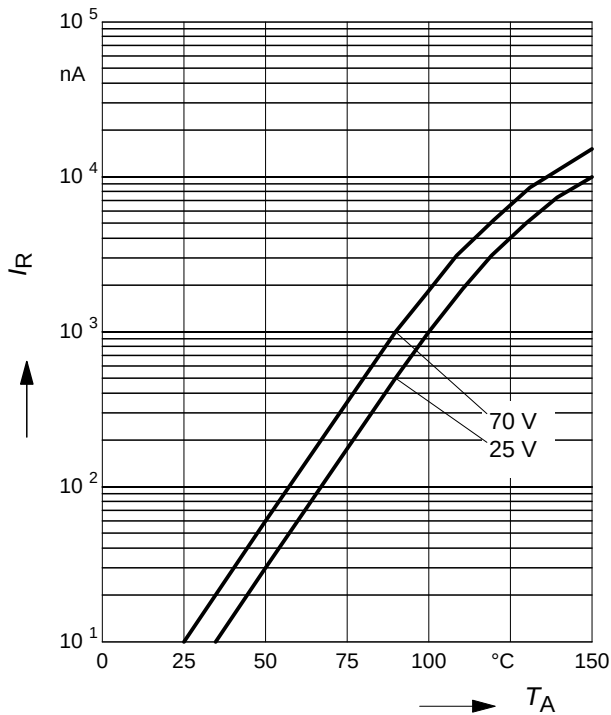
**Test circuit for reverse recovery time**


Pulse generator:  $t_p = 100\text{ns}$ ,  $D = 0.05$ ,  $t_r = 0.6\text{ns}$ ,  
 $R_i = 50\Omega$

Oscilloscope:  $R = 50\Omega$ ,  $t_r = 0.35\text{ns}$ ,  $C = 0.05\text{pF}$

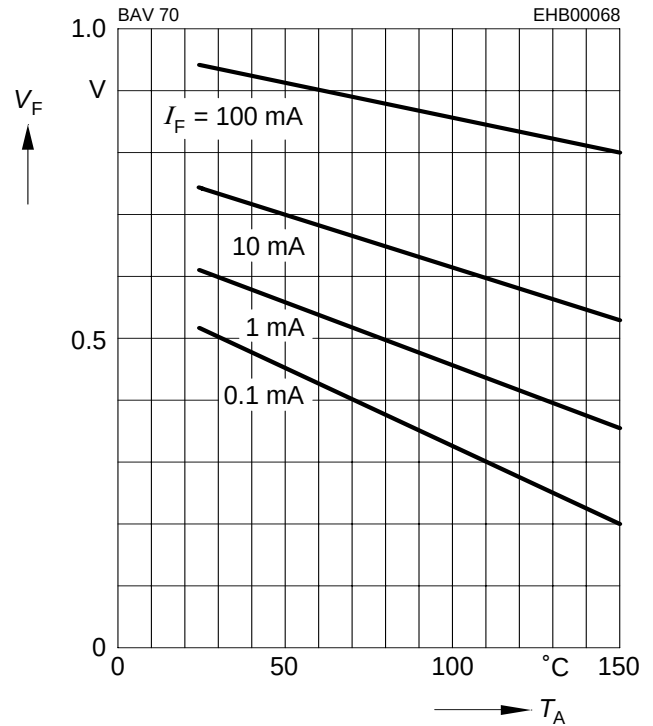
**Reverse current  $I_R = f(T_A)$**

$V_R = \text{Parameter}$



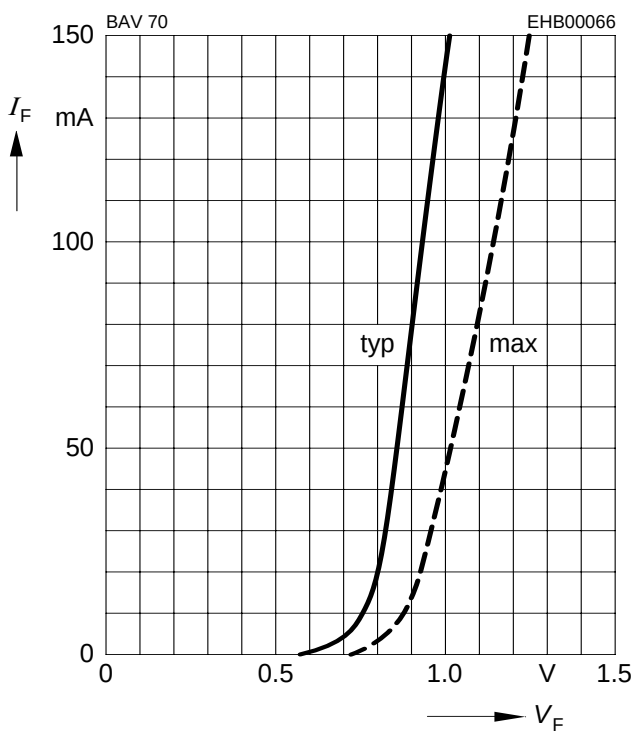
**Forward Voltage  $V_F = f(T_A)$**

$I_F = \text{Parameter}$



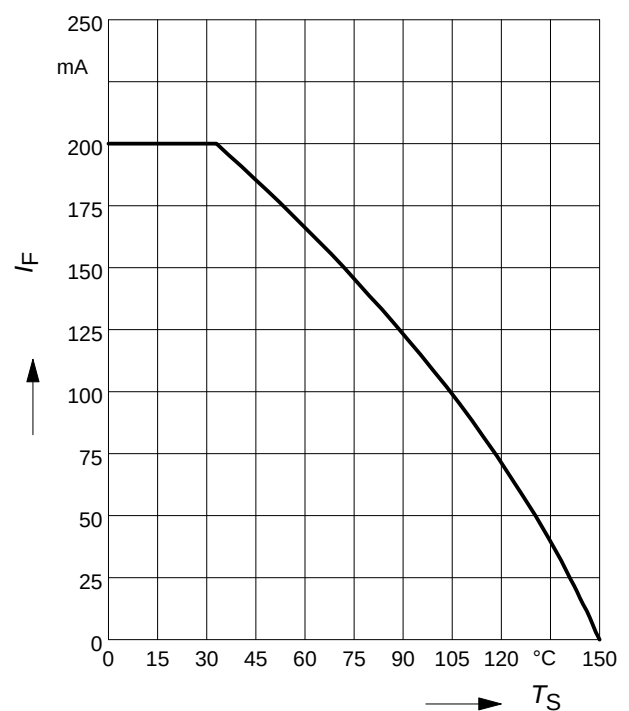
**Forward current  $I_F = f(V_F)$**

$T_A = 25^\circ\text{C}$



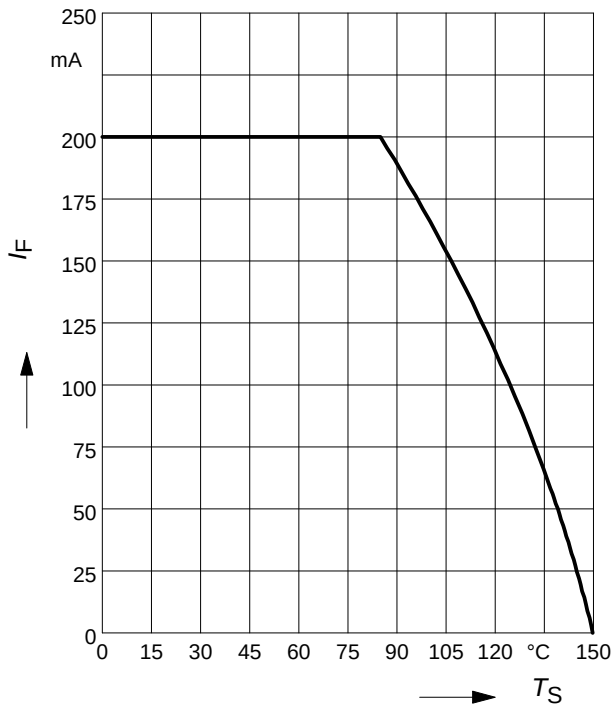
**Forward current  $I_F = f(T_S)$**

BAV70



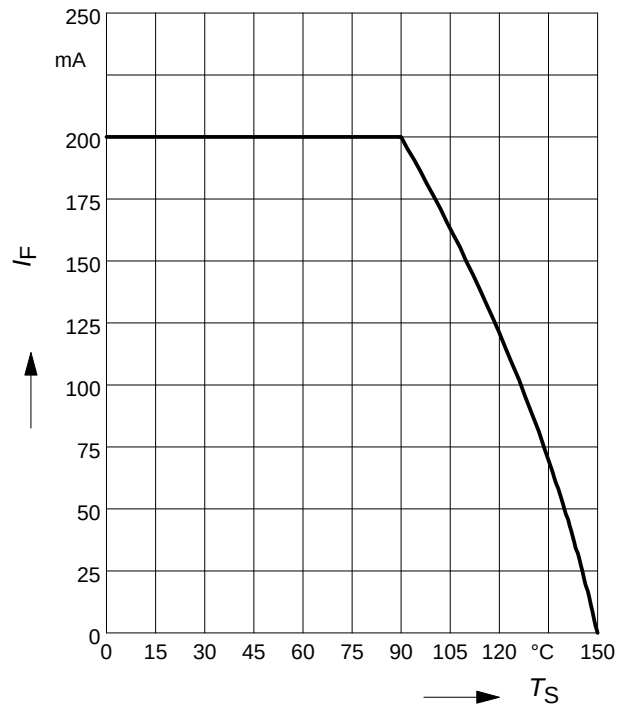
Forward current  $I_F = f(T_S)$

BAV70S



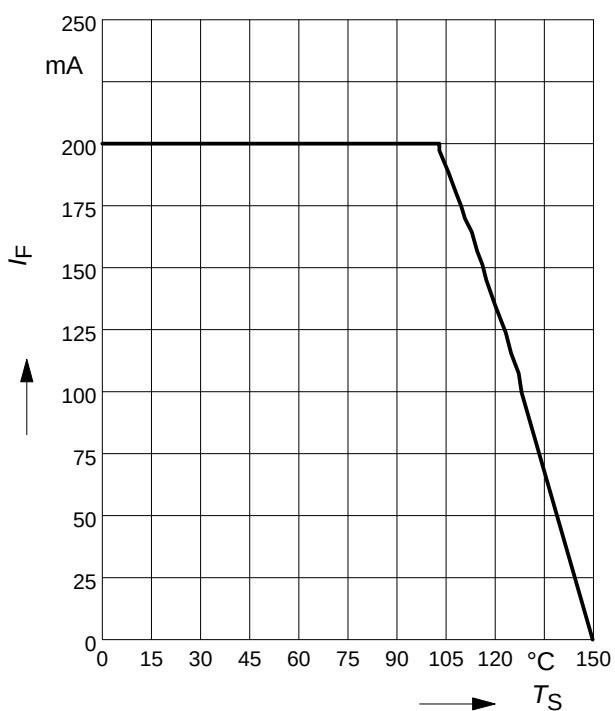
Forward current  $I_F = f(T_S)$

BAV70U



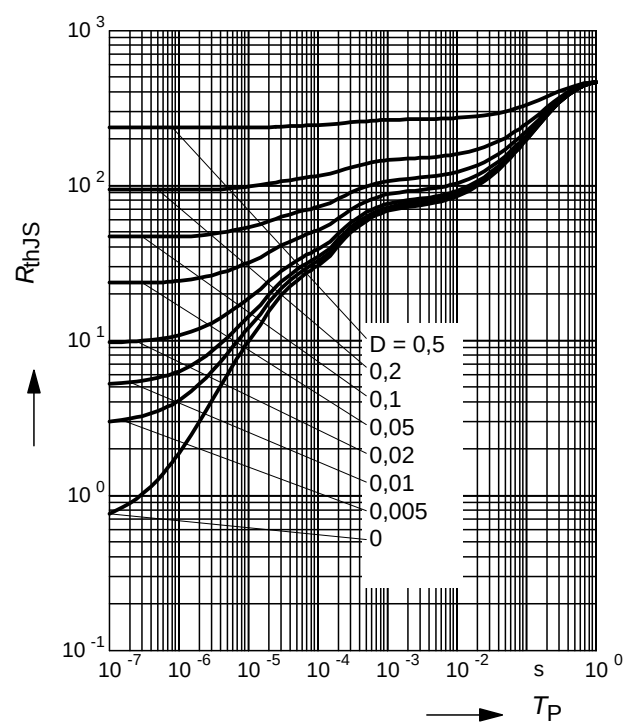
Forward current  $I_F = f(T_S)$

BAV70W



Permissible Puls Load  $R_{thJS} = f(t_p)$

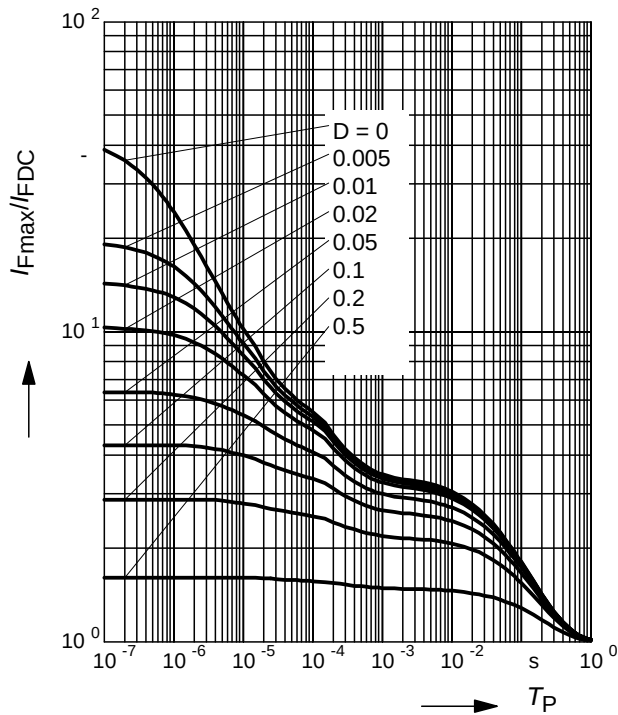
BAV70



### Permissible Pulse Load

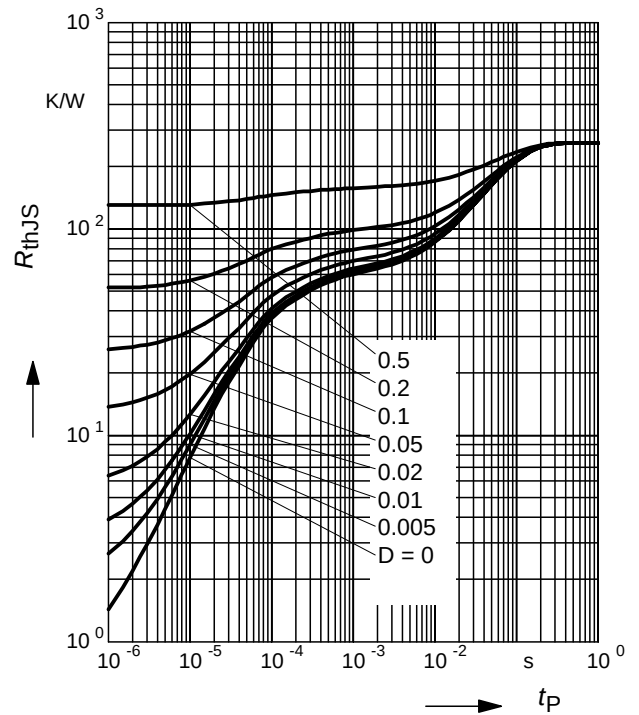
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAV70



### Permissible Puls Load $R_{thJS} = f(t_p)$

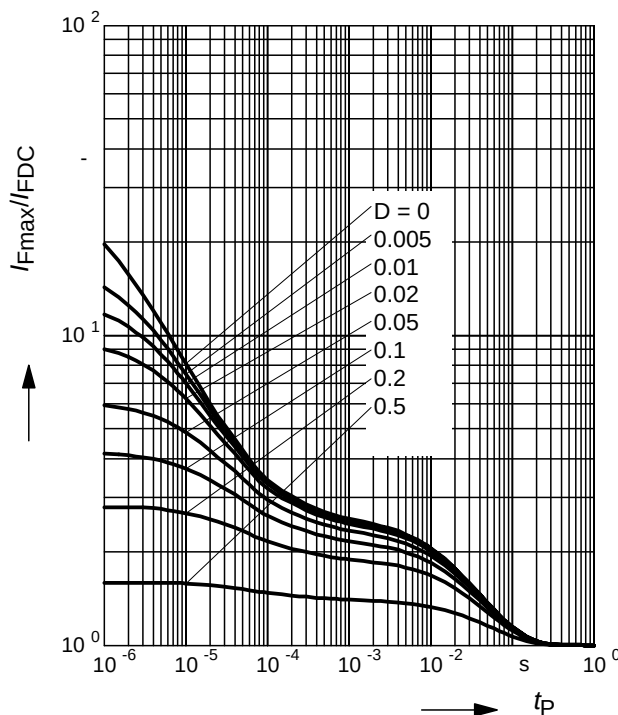
BAV70S



### Permissible Pulse Load

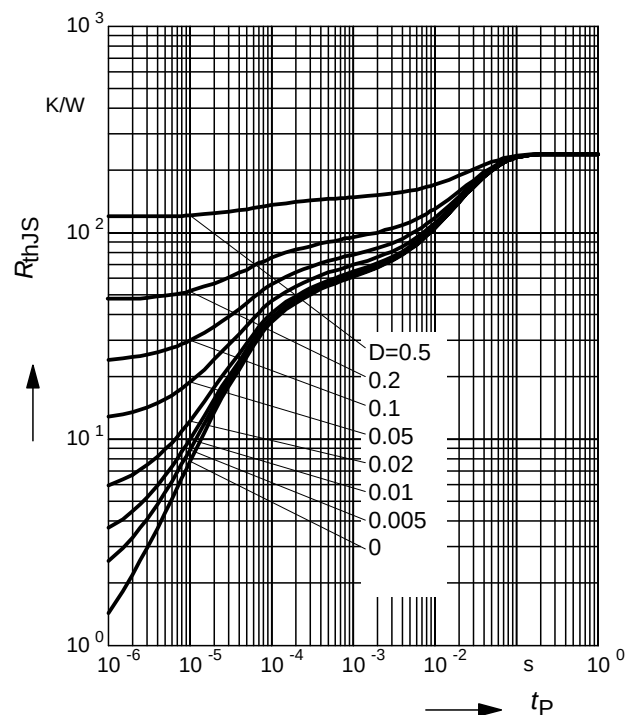
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAV70S



### Permissible Puls Load $R_{thJS} = f(t_p)$

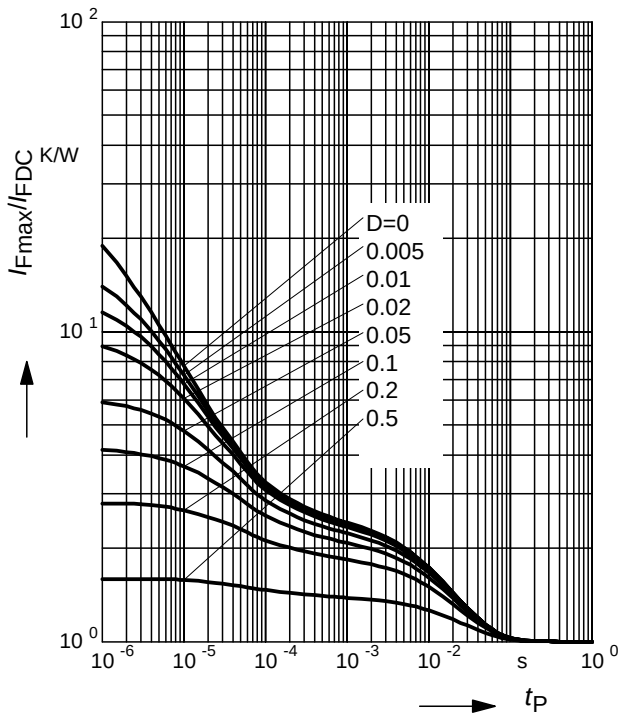
BAV70U



### Permissible Pulse Load

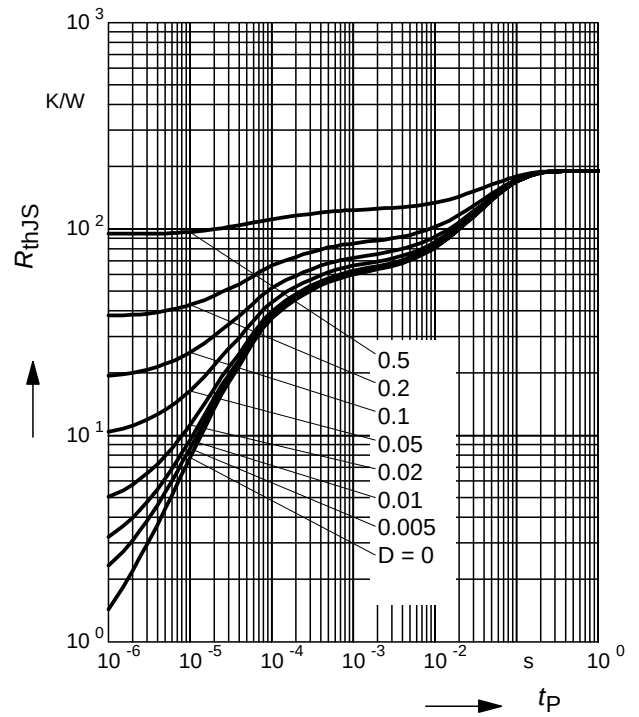
$$I_{Fmax}/I_{FDC} = f(t_p)$$

BAV70U



### Permissible Puls Load $R_{thJS} = f(t_p)$

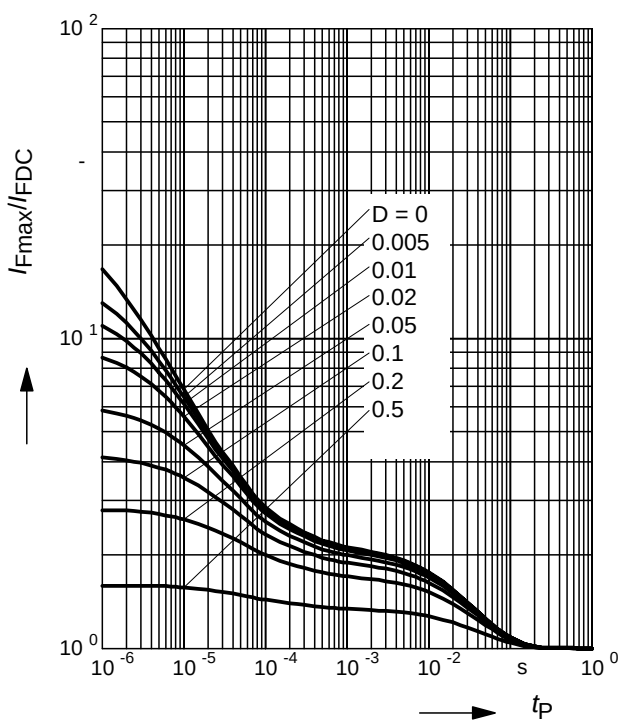
BAV70W



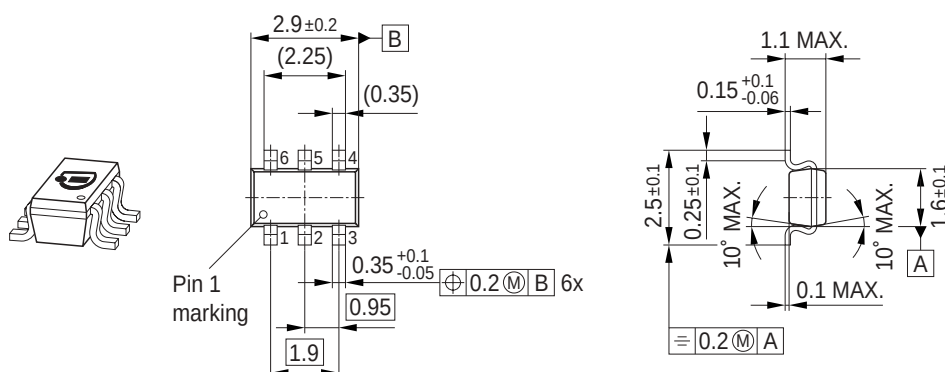
### Permissible Pulse Load

$$I_{Fmax}/I_{FDC} = f(t_p)$$

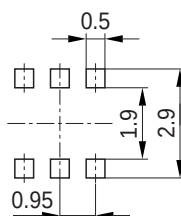
BAV70W



## Package Outline

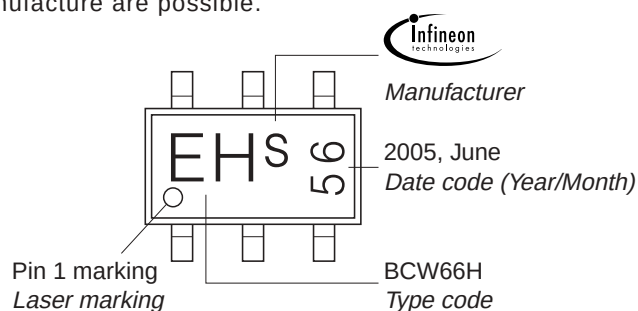


## Foot Print



## Marking Layout (Example)

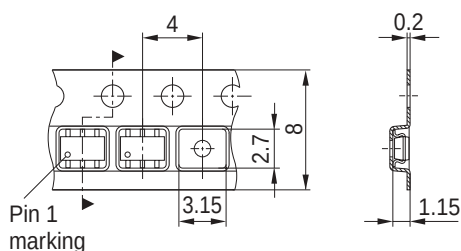
Small variations in positioning of Date code, Type code and Manufacture are possible.



## Standard Packing

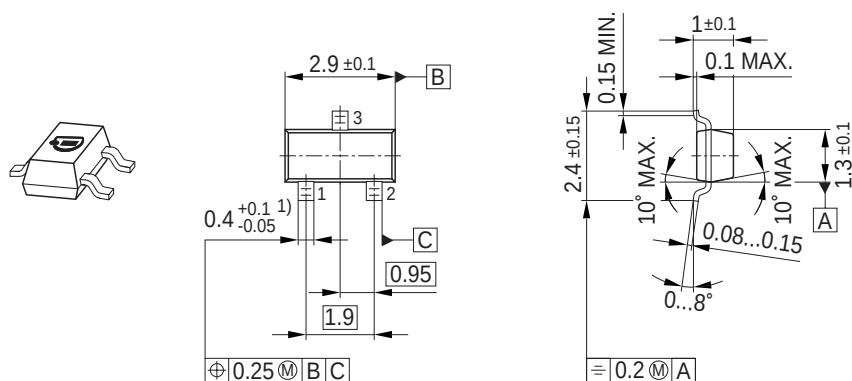
Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



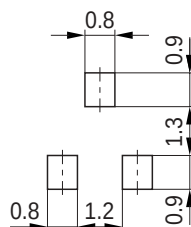


## Package Outline

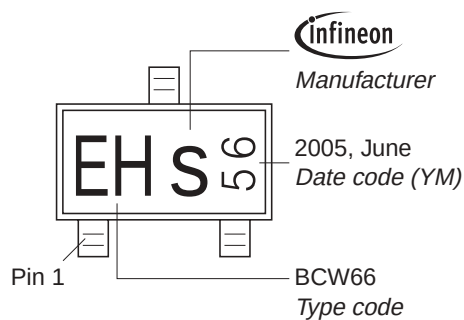


1) Lead width can be 0.6 max. in dambar area

## Foot Print

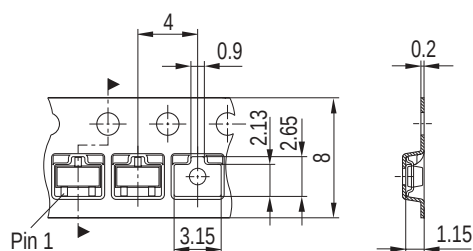


## Marking Layout (Example)

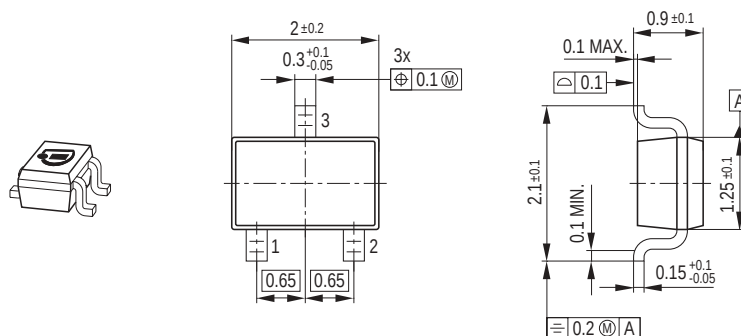


## Standard Packing

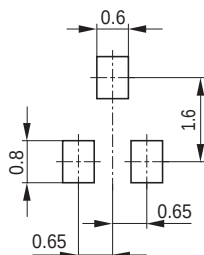
Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel



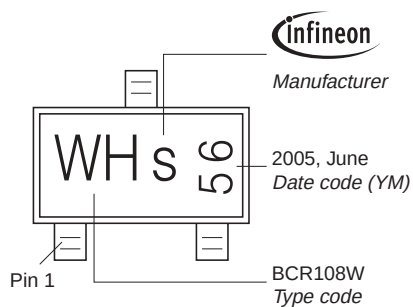
## Package Outline



## Foot Print

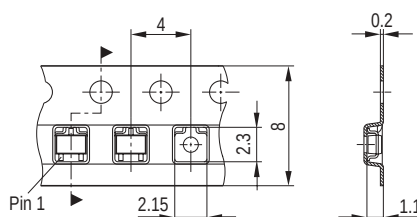


## Marking Layout (Example)

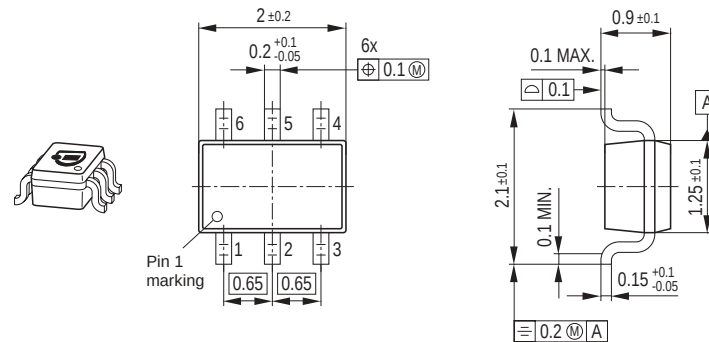


## Standard Packing

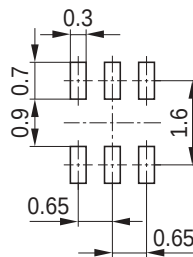
Reel  $\varnothing 180 \text{ mm}$  = 3.000 Pieces/Reel  
 Reel  $\varnothing 330 \text{ mm}$  = 10.000 Pieces/Reel



## Package Outline

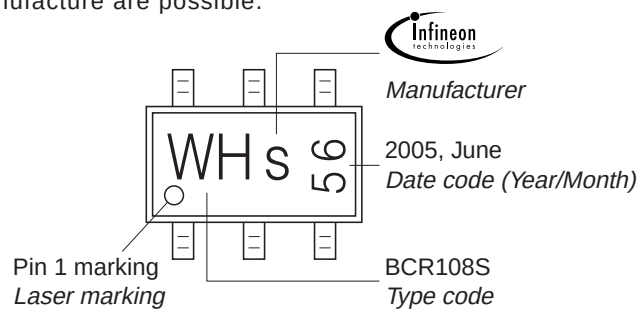


## Foot Print



## Marking Layout (Example)

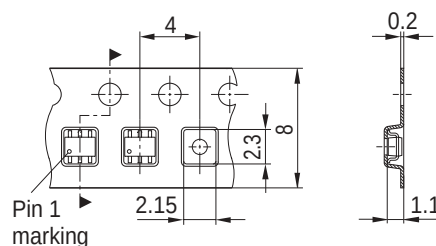
Small variations in positioning of Date code, Type code and Manufacture are possible.



## Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
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For symmetric types no defined Pin 1 orientation in reel.



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Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)

[www.lifeelectronics.ru](http://www.lifeelectronics.ru)